TOSHIBA Diode Silicon Epitaxial Planar Type

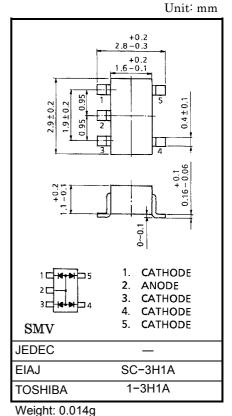
# **1SS308**

## Ultra High Speed Switching Applications

- Small package : SC-74A
- Low forward voltage  $: V_{F(3)} = 0.92V (typ.)$
- Fast reverse recovery time: t<sub>rr</sub> = 1.6ns (typ.)
- Small total capacitance  $: C_T = 2.2 pF (typ.)$

#### Maximum Ratings (Ta = 25°C)

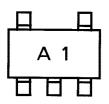
Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V <sub>RM</sub>	85	V
Reverse voltage	V <sub>R</sub>	80	V
Maximum (peak) forward current	I <sub>FM</sub>	300 (*)	mA
Average forward current	Ι <sub>Ο</sub>	100 (*)	mA
Surge current (10ms)	I <sub>FSM</sub>	2 (*)	А
Power dissipation	Р	200	mW
Junction temperature	Tj	125	°C
Storage temperature	T <sub>stg</sub>	-55~125	°C
(*) Unit rating. Total rating = unit rating × 1.5			



# **Electrical Characteristics (Ta = 25°C)**

Test Characteristic Symbol **Test Condition** Min Typ. Max Unit Circuit 0.61 V<sub>F (1)</sub>  $I_F = 1mA$ \_\_\_\_ \_\_\_\_ \_\_\_\_ Forward voltage 0.74 V<sub>F (2)</sub>  $I_F = 10mA$ V I<sub>F</sub> = 100mA 0.92 1.20 V<sub>F (3)</sub> \_ \_\_\_\_ V<sub>R</sub> = 30V 0.1 I<sub>R (1)</sub> \_\_\_\_ \_\_\_\_ \_ Reverse current μΑ V<sub>R</sub> = 80V 0.5 I<sub>R (2)</sub> \_\_\_\_ \_ \_ Total capacitance  $C_{\mathsf{T}}$ V<sub>R</sub> = 0, f = 1MHz 2.2 4.0 pF I<sub>F</sub> = 10mA, Fig.1 1.6 4.0 Reverse recovery time t<sub>rr</sub> \_ ns

### Marking



# **TOSHIBA**

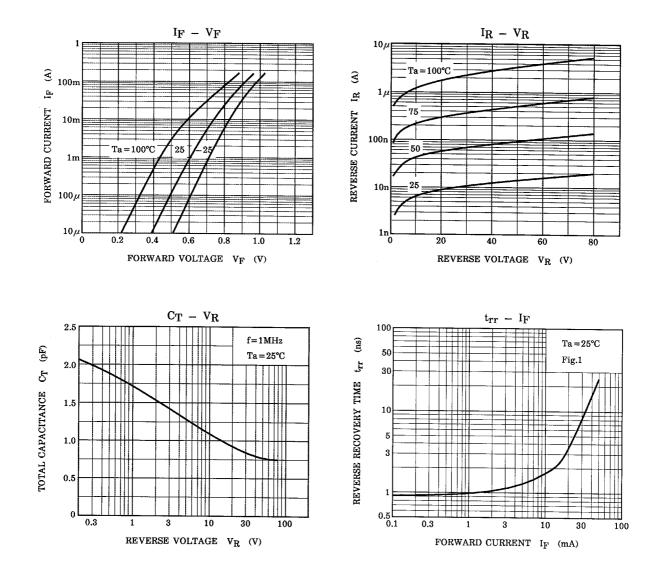
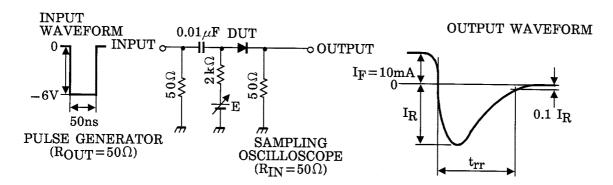


Fig.1 Reverse Recovery Time (trr) Test Circuit



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